

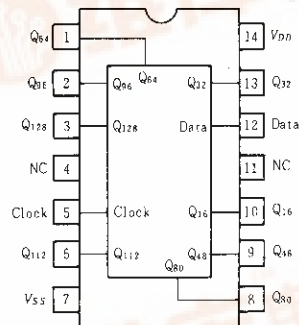
128-bit Static Shift Register

The HD14562B is a 128-bit static shift register. Data is clocked in and out of the shift register on the positive edge of the clock input. Data outputs are available every 16 bits, from 16 through bit 128.

FEATURES

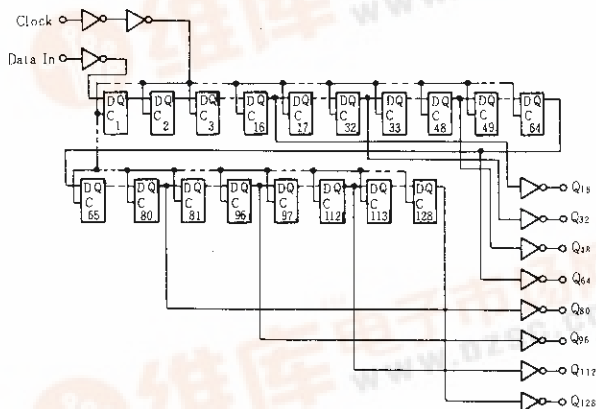
- Noise Immunity = 45% of V_{DD} typ.
- Single Supply Operation ... Positive or Negative
- Fully Static Operation
- Exceedingly Slow Input Transition Rates May Be Applied to the
- Clock Input
- 5.6MHz Operation @10V
- Cascadable to Provide Longer Shift Register Lengths ... 1.5MHz Operation @10V
- Supply Voltage Range = 3 to 18V
- Capable of Driving One Low-power Schottky TTL Load Over the Rated Temperature Range

PIN ARRANGEMENT

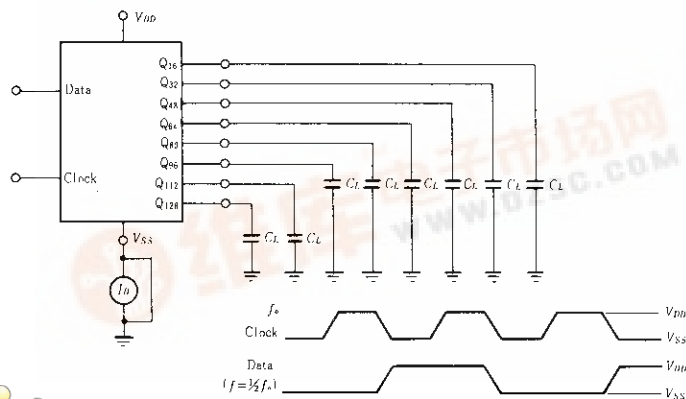


(Top View)

LOGIC DIAGRAM



POWER DISSIPATION TEST CIRCUIT AND WAVEFORM



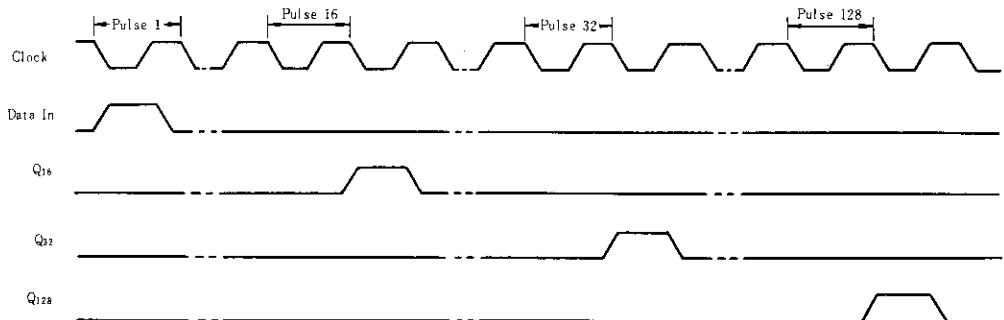
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	$V_{DD}(V)$	Test Conditions	-40°C		25°C			85°C		Unit
				min	max	min	typ	max	min	max	
Output Voltage	V_{OL}	5.0	$V_{in} = V_{DD}$ or 0	—	0.05	—	0	0.05	—	0.05	V
		10		—	0.05	—	0	0.05	—	0.05	
		15		—	0.05	—	0	0.05	—	0.05	
	V_{OH}	5.0	$V_{in} = 0$ or V_{DD}	4.95	—	4.95	5.0	—	4.95	—	V
		10		9.95	—	9.95	10	—	9.95	—	
		15		14.95	—	14.95	15	—	14.95	—	
Input Voltage	V_{IL}	5.0	$V_{ext} = 4.5$ or $0.5V$	—	1.5	—	2.25	1.5	—	1.5	V
		10	$V_{ext} = 9.0$ or $1.0V$	—	3.0	—	4.50	3.0	—	3.0	
		15	$V_{ext} = 13.5$ or $1.5V$	—	4.0	—	6.75	4.0	—	4.0	
	V_{IH}	5.0	$V_{ext} = 0.5$ or $4.5V$	3.5	—	3.5	2.75	—	3.5	—	V
		10	$V_{ext} = 1.0$ or $9.0V$	7.0	—	7.0	5.50	—	7.0	—	
		15	$V_{ext} = 1.5$ or $13.5V$	11.0	—	11.0	8.25	—	11.0	—	
Output Drive Current	I_{OH}	5.0	$V_{OH} = 2.5V$	-1.0	—	-0.8	-1.7	—	-0.6	—	mA
		5.0	$V_{OH} = 4.6V$	-0.2	—	-0.16	-0.36	—	-0.12	—	
		10	$V_{OH} = 9.5V$	-0.5	—	-0.4	-0.9	—	-0.3	—	
		15	$V_{OH} = 13.5V$	-1.4	—	-1.2	-3.5	—	-1.0	—	
	I_{OL}	5.0	$V_{OL} = 0.4V$	0.52	—	0.44	0.88	—	0.36	—	mA
		10	$V_{OL} = 0.5V$	1.3	—	1.1	2.25	—	0.9	—	
		15	$V_{OL} = 1.5V$	3.6	—	3.0	8.8	—	2.4	—	
Input Current	I_{in}	15		—	± 0.3	—	± 0.00001	± 0.3	—	± 1.0	μA
Input Capacitance	C_{in}		$V_{in} = 0$	—	—	—	5.0	7.5	—	—	pF
Quiescent Current	I_{DD}	5.0	Zero Signal, per Package	—	50	—	0.010	50	—	375	μA
		10		—	100	—	0.020	100	—	750	
		15		—	200	—	0.030	200	—	1500	
Total Supply Current*	I_T	5.0	Dynamic + I_{DD} , per Gate	—	—	—	1.94	—	—	—	μA
		10		—	—	—	3.81	—	—	—	
		15		—	—	—	5.52	—	—	—	

* To calculate total supply current at frequency other than 1kHz.

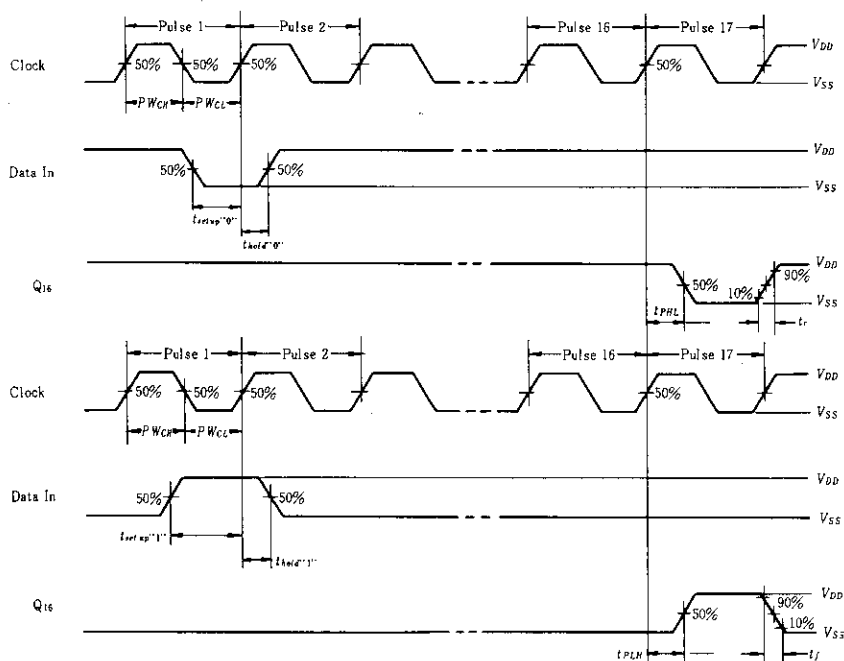
@ $V_{DD} = 5.0V$ $I_T = (1.94 \mu A/kHz)f + I_{DD}$, @ $V_{DD} = 10V$ $I_T = (3.81 \mu A/kHz)f + I_{DD}$, @ $V_{DD} = 15V$ $I_T = (5.52 \mu A/kHz)f + I_{DD}$

TIMING DIAGRAM

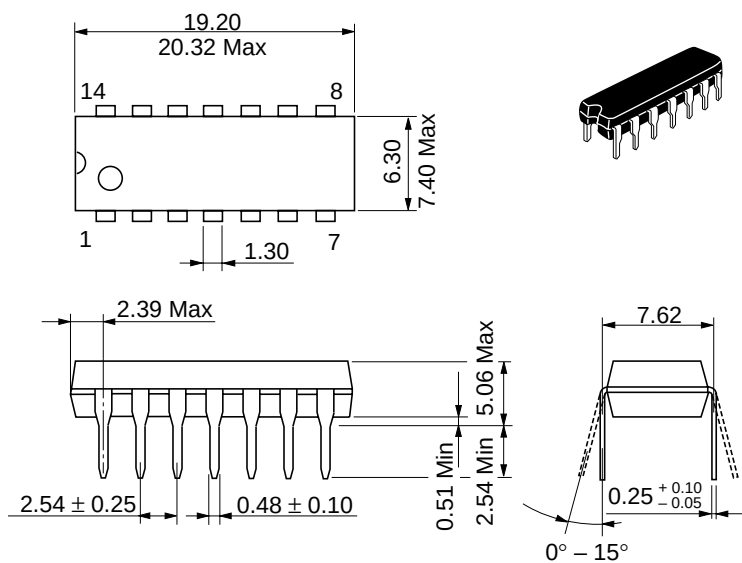


SWITCHING CHARACTERISTICS ($C_L=50\text{pF}$, $T_a=25^\circ\text{C}$)

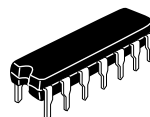
Characteristic	Symbol	$V_{DD}(\text{V})$	min	typ	max	Unit
Output Rise Time	t_r	5.0	—	180	400	ns
		10	—	90	200	
		15	—	65	160	
Output Fall Time	t_f	5.0	—	100	200	ns
		10	—	50	100	
		15	—	37	80	
Propagation Delay Time	t_{PLH} , t_{PHL}	5.0	—	600	1500	ns
		10	—	250	660	
		15	—	170	500	
Clock Pulse Width	PW_C	5.0	900	300	—	ns
		10	330	110	—	
		15	250	75	—	
Clock Frequency	PRF	5.0	—	1.9	0.8	MHz
		10	—	5.6	1.5	
		15	—	8.0	2.0	
Setup Time	t_{setup} "1"	5.0	-20	-170	—	ns
		10	-10	-64	—	
		15	0	-60	—	
	t_{setup} "0"	5.0	-20	-91	—	ns
		10	-10	-58	—	
		15	0	-40	—	
Hold Time	t_{hold} "1"	5.0	350	263	—	ns
		10	165	109	—	
		15	155	100	—	
	t_{hold} "0"	5.0	350	267	—	ns
		10	200	140	—	
		15	140	93	—	

AC Test Waveform


Note) The remaining Data-Bit Outputs (Q_{12} , Q_{14} , Q_{16} , Q_{18} , Q_{20} , Q_{22} and Q_{24}) will occur at Clock Pulse 32, 48, 64, 80, 96, 112, 128 in the same relationship as Q_{16} .



Unit: mm



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